NSN 5962-01-305-7736

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high to low level

View Online at https://aerobasegroup.com/nsn/5962-01-305-7736

Bod	ly Length:
1.29	10 inches
Bod	ly Width:
0.61	0 inches
Bod	ly Height:
0.15	i0 inches
Мах	imum Power Dissipation Rating:
1.0	watts
Оре	erating Tempurature Range:
-55.	0/+125.0 degrees celsius
Stor	rage Tempurature Range:
-65.	0/+150.0 degrees celsius
Fea	tures Provided:
Mon	olithic and bipolar and schottky and programmable and w/active pull-up
Incl	osure Material:
Cera	amic
Incl	osure Configuration:
Dua	I-in-line
Out	put Logic Form:
Trar	nsistor-transistor logic
Inpu	ut Circuit Pattern:
13 ir	nput
Cas	e Outline Source And Designator:
D-3	mil-m-38510
Terr	ninal Surface Treatment:
Solo	ler
Volt	age Rating And Type Per Characteristic:
7.0	volts power source
Tim	e Rating Per Chacteristic:
90.0	0 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, h
outp	put
Men	nory Device Type:
Rom	1
Tes	t Data Document:
969	06-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terr	ninal Type And Quantity:
24 p	printed circuit
She	If Life:
N/a	
Unit	t Of Measure:
	nilitarization:
Yes	- demil/mli

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